

# Elenco completo delle pubblicazioni di Andrea Neviani

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- [R.49] F. Padovan, M. Tiebout, **A. Neviani** and A. Bevilacqua, "A 12 GHz 22 dB-Gain-Control SiGe Bipolar VGA With 2° Phase-Shift Variation," in *IEEE Journal of Solid-State Circuits*, vol. 51, no. 7, pp. 1525-1536, July 2016.  
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